# New ternary phases in the Lu–Ni–Si system

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The existence of three new ternary compounds, LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub>, was established in the Lu–Ni–Si system, and their crystal structures were refined from X-ray powder diffraction data. The structure of the compound LuNiSi<sub>3</sub> belongs to the structure type SmNiGe<sub>3</sub>, Pearson symbol *oS20*, space group *Cmmm*, a = 3.88279(8), b = 20.8179(4), c = 3.89111(8) Å, that of LuNiSi to the structure type TiNiSi, *oP12*, *Pnma*, a = 6.67857(10), b = 4.09340(6), c = 7.11618(10) Å, and that of LuNi<sub>0.61(2)</sub>Si<sub>1.39(2)</sub> to the structure type AlB<sub>2</sub>, *hP3*, *P6/mmm*, a = 3.94594(10), c = 3.87276(10) Å. The compound LuNi<sub>0.61</sub>Si<sub>1.39</sub> has a homogeneity range of LuNi<sub>0.27-0.67</sub>Si<sub>1.73-1.33</sub> at 600°C and is characterized by a statistical mixture of Ni and Si atoms. The other two compounds have point compositions and ordered distribution of the atoms.

Intermetallic compound / Lutetium / Nickel / Silicon / X-ray powder diffraction / Crystal structure

# 1. Introduction

The results presented in this paper are part of a systematic investigation of crystal structures of ternary compounds formed in R–T–Si systems (where R is a rare-earth element and T is a transition element), in this case in the system Lu–Ni–Si. This system has to our knowledge not been investigated in the whole concentration range; the literature contains information about six ternary compounds [1,2], for which crystallographic data are given in Table 1.

Three new phases, LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub>, were found during our investigation of the phase equilibria in the system Lu–Ni–Si at 600°C. We present here results of the crystal structure determination of the three new silicides using X-ray powder diffraction. Preliminary results of the investigation were presented in [3].

# 2. Experimental

The samples were prepared from pure elements by arc melting under an argon atmosphere. The alloys were remelted to ensure homogeneity. The composition of the samples was controlled by comparing the mass of the obtained alloy with the mass of the initial load. The weight losses did not exceed 2% after melting. The samples were annealed at 600°C under vacuum in quartz ampoules for one month and subsequently quenched in cold water. The crystal structures of the

compounds LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub> were determined from X-ray powder diffraction data collected at room temperature on a diffractometer Stoe Stadi P equipped with a linear position-sensitive detector and Cu K $\alpha_1$ -radiation (range 6-110° 2 $\theta$ , step size 0.015°) on alloys of nominal compositions  $Lu_{20}Ni_{20}Si_{60}$ ,  $Lu_{33,3}Ni_{33,3}Si_{33,3}$ , and  $Lu_{33,3}Ni_{21,3}Si_{45,3}$ , respectively. Experimental details and parameters from the structure refinements by the Rietveld method using the program package FullProf Suite [10] are given in Table 2. Starting atom coordinates for the refinements were taken from the corresponding prototypes [1]. In the final cycles the following parameters were allowed to vary for each single-phase pattern: sample shift, scale factor, cell parameters, profile parameters (pseudo-Voigt profile function), atom positional and displacement parameters, site occupancy (in the case of LuNi<sub>0.61</sub>Si<sub>1.39</sub>), and preferred orientation parameter. For the refinement of the structure of LuNiSi3, the isotropic displacement parameters of atoms of the same chemical element were constrained to be equal. The background was defined by linear interpolation between manually assigned points (LuNiSi<sub>3</sub>), or by polynomial functions using a Fourier filtering technique (LuNiSi and LuNi<sub>0.61</sub>Si<sub>1.39</sub>). Fig. 1 shows the powder diffraction patterns of the alloys Lu<sub>20</sub>Ni<sub>20</sub>Si<sub>60</sub>, Lu<sub>33,3</sub>Ni<sub>33,3</sub>Si<sub>33,3</sub>, and Lu<sub>33,3</sub>Ni<sub>21,3</sub>Si<sub>45,3</sub>. The cell parameters within the homogeneity range of the ternary AlB<sub>2</sub>-type phase,  $LuNi_{0.27-0.67}Si_{1.73-1.33}$ , were refined using the program package FullProf Suite [10].

Compound	Structure	Pearson	Space	Ce	ell parameters,	Å	Literature
Compound	type	symbol	group	а	b	С	Literature
LuNi <sub>10</sub> Si <sub>2</sub>	$Nd(Mn_{0.5}Fe_{0.5})_4Fe_8$	<i>tI</i> 26	I4/mmm	8.164	_	4.650	[4]
LuNi <sub>5</sub> Si <sub>3</sub>	YNi <sub>5</sub> Si <sub>3</sub>	oP36	Pnma	18.49	3.739	6.710	[5]
LuNi <sub>2</sub> Si <sub>2</sub>	CeAl <sub>2</sub> Ga <sub>2</sub>	<i>tI</i> 10	I4/mmm	3.905	-	9.495	[6]
LuNiSi3	SmNiGe <sub>3</sub>	oS20	Cmmm	3.88279(8)	20.8179(4)	3.89111(8)	This work
Lu <sub>3</sub> Ni <sub>6</sub> Si <sub>2</sub>	Ce <sub>3</sub> Ni <sub>6</sub> Si <sub>2</sub>	<i>cI</i> 44	Im-3m	8.659	_	_	[7]
Lu <sub>2</sub> Ni <sub>3</sub> Si <sub>5</sub>	Lu <sub>2</sub> Co <sub>3</sub> Si <sub>5</sub>	<i>mS</i> 40	C2/c	11.032	11.942	5.919	[8]
					$\beta = 120.18^{\circ}$		
LuNiSi <sub>2</sub>	CeNiSi <sub>2</sub>	oS16	Cmcm	3.851	15.810	3.851	[9]
LuNiSi	TiNiSi	oP12	Pnma	6.67857(10)	4.09340(6)	7.11618(10)	This work
LuNi <sub>0.61(2)</sub> Si <sub>1.39(2)</sub>	AlB <sub>2</sub>	hP3	P6/mmm	3.94594(10)	_	3.87276(10)	This work

Table 1 Crystallographic data of the ternary compounds in the system Lu–Ni–Si.

Table 2 Experimental details and crystallographic data for the compounds  $LuNiSi_3$ , LuNiSi, and  $LuNi_{0.61}Si_{1.39}$ .

Compound	LuNiSi3	LuNiSi	LuNi <sub>0.61(2)</sub> Si <sub>1.39(2)</sub>
Structure type	SmNiGe <sub>3</sub>	TiNiSi	$AlB_2$
Pearson symbol	oS20	oP12	hP3
Space group	Cmmm	Pnma	P6/mmm
Cell parameters: $a, Å$	3.88279(8)	6.67857(10)	3.94594(10)
b, Å	20.8179(4)	4.09340(6)	_
<i>c</i> , Å	3.89111(8)	7.11618(10)	3.87276(10)
Cell volume V, $Å^3$	314.525(11)	194.543(5)	52.222(2)
Number of formula units in the cell Z	4	4	1
Density $D_{\rm X}$ , g/cm <sup>3</sup>	6.714	8.937	7.948
Preferred orientation: value / [direction]	0.935(3) / [101]	0.9158(13) / [010]	0.915(3) / [110]
Profile parameters: U	0.054(2)	0.089(12)	0.023(2)
V	-0.0232(16)	0.0070(14)	-0.001(2)
W	0.0154(3)	0.0107(3)	0.0110(5)
Shape parameter	0.511(12)	0.214(3)	0.176(14)
Asymmetry parameters: $P_1$	0.0806(14)	0.078(3)	0.091(5)
$P_2$	0.0211(6)	0.0126(9)	0.0151(13)
Number of refined parameters	20	21	14
Reliability factors: $R_{\rm B}$	0.0658	0.0543	0.0758
$R_F$	0.0535	0.0482	0.0543
$R_{ m p}$	0.0714	0.0613	0.0883
$R_{\rm wp}^{\rm r}$	0.102	0.0823	0.126
	16.1	5.01	7.54

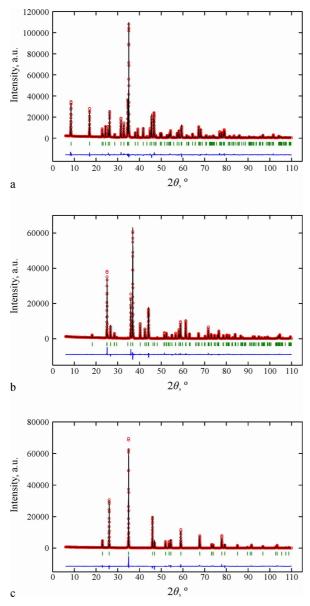
#### 3. Results and discussion

The crystal structures of the compounds LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub> were refined in the space groups *Cmmm*, *Pnma*, and *P6/mmm*, as belonging to the structure types SmNiGe<sub>3</sub> [11], TiNiSi [12], and AlB<sub>2</sub> [13], respectively. Atom coordinates, isotropic displacement parameters, interatomic distances, and coordination numbers for the compounds LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub> are listed in Tables 3-8.

The structure of the compound LuNiSi<sub>3</sub> (SmNiGe<sub>3</sub> type) is an intergrowth of slabs sliced from the simple structure types BaAl<sub>4</sub> (or its ternary variant CeAl<sub>2</sub>Ga<sub>2</sub>), AlB<sub>2</sub>, and  $\alpha$ -Po [14]. The fragments have the following compositions: Lu<sub>0.5</sub>NiSi (CeAl<sub>2</sub>Ga<sub>2</sub>)

type), LuSi<sub>2</sub> (AlB<sub>2</sub> type), and Si<sub>2</sub> ( $\alpha$ -Po type). They are stacked along the crystallographic direction [010] *via* common atoms forming square meshes. The composition of the compound can be obtained from the stacking of eight slabs in the translation unit: 2(Lu<sub>0.5</sub>NiSi + LuSi<sub>2</sub> + Lu<sub>0.5</sub>NiSi + Si<sub>2</sub>)  $\equiv$ 4LuNiSi<sub>3</sub>. It should be noted that the parent structure types CeAl<sub>2</sub>Ga<sub>2</sub> and AlB<sub>2</sub> are represented in the system Lu–Ni–Si by the ternary compounds LuNi<sub>2</sub>Si<sub>2</sub> and LuNi<sub>0.61</sub>Si<sub>1.39</sub> (or binary LuSi<sub>1.67</sub> [15]), respectively.

The structure of the compound LuNiSi (TiNiSi type) is a deformation derivative of the structure type ZrBeSi, which is a ternary substitution variant of the structure type  $AlB_2$  [14].

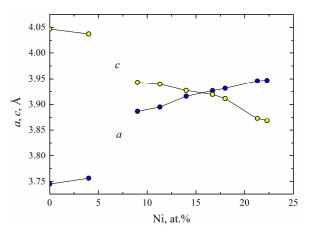


**Fig. 1** Experimental (circles), calculated (continuous line) and difference between experimental and calculated (bottom) X-ray powder diffraction patterns of the samples  $Lu_{20}Ni_{20}Si_{60}$  (a),  $Lu_{33.3}Ni_{33.3}Si_{33.3}$  (b), and  $Lu_{33.3}Ni_{21.3}Si_{45.3}$  (c) (Cu  $K\alpha_1$ -radiation). Vertical bars indicate the positions of reflections from the compounds LuNiSi<sub>3</sub> (a), LuNiSi (b), and LuNi<sub>0.61</sub>Si<sub>1.39</sub> (c).

The phase LuNi<sub>0.61</sub>Si<sub>1.39</sub>, which has a statistical mixture of Ni and Si atoms (unlike the phases LuNiSi<sub>3</sub> and LuNiSi, which are ternary compounds with point compositions and ordered distribution of all the atoms in the crystal structure), could be part of the solid solution based on the binary silicide LuSi<sub>1.67</sub>. However, our investigations show that at 600°C the composition LuNi<sub>0.61</sub>Si<sub>1.39</sub> is inside the homogeneity range LuNi<sub>0.27-0.67</sub>Si<sub>1.73-1.33</sub> of a ternary phase with hexagonal AlB<sub>2</sub>-type structure. The

cell parameters within the homogeneity range are shown in Fig. 2. With increasing Ni content (from 9 to 22.3 at.%) the *a*-parameter increases (3.88700(7)-3.94674(6) Å), whereas the *c*-parameter decreases (3.94298(10)-3.86807(7) Å), the c/a-ratio changing from 1.014 to 0.979. Consequently, the distances between the small atoms in the hexagonal nets increase from 2.244 to 2.279 Å. Considering the atomic and covalent radii of Si and Ni ( $r_{at} = 1.32$  and  $r_{\rm cov} = 1.11$  Å for Si,  $r_{\rm at} = 1.24$  and  $r_{\rm cov} = 1.15$  Å for Ni), one can conclude that these atoms are connected via covalent bonding. The ratio c/a = 1(which corresponds to an ideal trigonal prism Lu<sub>6</sub> around the small atoms) should be observed for 15.7 at.% Ni (LuNi<sub>0.47</sub>Si<sub>1.53</sub>). The binary compound LuSi<sub>167</sub> dissolves about 4 at.% Ni. The cell parameters within this solid solution change in the same way as for the isotypic ternary phase LuNi<sub>0.27-0.67</sub>Si<sub>1.73-1.33</sub>.

The structures of the three new compounds belong to class 10 of the systematic by P. Kripyakevich [16], which groups structure types with coordination number 6+n and coordination polyhedra having the form of a trigonal prism with 0-5 additional vertices for the small atoms. In the case of LuNiSi<sub>3</sub> (structure type SmNiGe<sub>3</sub>), the trigonal prisms around the Si atoms have the composition Lu<sub>6</sub> or Lu<sub>2</sub>Si<sub>4</sub> and their faces are capped by 1Ni + 2Si or 2Ni + 1Si atoms, respectively. In LuNiSi (TiNiSi) and LuNi<sub>0.61</sub>Si<sub>1.39</sub> (AlB<sub>2</sub>), the trigonal prisms around the Si are built up exclusively from Lu atoms and the additional atoms are four Ni (LuNiSi) or 3M (LuNi<sub>0.61</sub>Si<sub>1.39</sub>, M = 0.307Ni + 0.693Si). The coordination polyhedra of the Ni atoms are square antiprisms of composition  $Lu_4Si_4$  with one additional Si atom (LuNiSi<sub>3</sub>), or trigonal prisms of composition Lu<sub>6</sub> with four Si (LuNiSi) or three M additional atoms (LuNi<sub>0.61</sub>Si<sub>1.39</sub>). The closest atoms around the Lu atoms form 20- (LuNiSi<sub>3</sub> and LuNi<sub>0.61</sub>Si<sub>1.39</sub>) or 16- (LuNiSi) vertex polyhedra.



**Fig. 2** Cell parameters *versus* Ni content within the homogeneity range of the ternary phase  $LuNi_{0.27-0.67}Si_{1.73-1.33}$  with AlB<sub>2</sub>-type structure.

**Table 3** Atom coordinates and isotropic displacement parameters for the compound LuNiSi<sub>3</sub> (structure type SmNiGe<sub>3</sub>, *oS*20, *Cmmm*).

Site	Wyckoff position	X	у	Z	$B_{\rm iso},{ m \AA}^2$
Lu	4 <i>j</i>	0	0.33119(3)	1/2	0.411(17)
Ni	4i	0	0.11183(9)	0	1.00(5)
Si1	4 <i>j</i>	0	0.05683(18)	1/2	0.89(5)
Si2	4i	0	0.21541(18)	0	0.89(5)
Si3	4i	0	0.44459(18)	0	0.89(5)

**Table 4** Interatomic distances and coordination numbers for the compound LuNiSi<sub>3</sub> (structure type SmNiGe<sub>3</sub>, *oS*20, *Cmmm*).

Atom		$\delta$ , Å	CN	Atom		$\delta$ , Å	CN
Lu	- 4 Si2	2.9147(13)		Si1	- 2 Ni	2.257(2)	
	– 4 Ni	2.9935(9)			– 1 Si1	2.366(5)	9
	- 2 Si1	3.034(3)			– 4 Si3	2.74865(7)	9
	– 2 Si3	3.059(3)	20		– 2 Lu	3.034(3)	
	– 2 Si2	3.098(3)	20	Si2	– 1 Ni	2.156(4)	
	– 2 Lu	3.88279(8)			– 2 Si2	2.417(3)	9
	– 2 Lu	3.89111(8)			– 4 Lu	2.9147(13)	9
	– 2 Lu	3.8982(8)			– 2 Lu	3.098(3)	
Ni	- 1 Si2	2.156(4)		Si3	- 2 Ni	2.269(2)	
	- 2 Si1	2.257(2)	9		– 1 Si3	2.307(6)	9
	– 2 Si3	2.269(2)	9		– 4 Si1	2.74865(7)	9
	– 4 Lu	2.9935(9)			– 2 Lu	3.059(3)	

**Table 5** Atom coordinates and isotropic displacement parameters for the compound LuNiSi (structure type TiNiSi, *oP*12, *Pnma*).

Site	Wyckoff position	x	У	Z	$B_{\rm iso},{ m \AA}^2$
Lu	4 <i>c</i>	-0.00555(16)	1⁄4	0.70197(8)	0.390(13)
Ni	4c	0.1882(4)	1⁄4	0.0777(5)	0.53(6)
Si	4 <i>c</i>	0.3034(9)	1⁄4	0.4090(9)	1.67(12)

**Table 6** Interatomic distances and coordination numbers for the compound LuNiSi (structure type TiNiSi, *oP*12, *Pnma*).

Atom		<i>δ</i> , Å	CN	Atom		<i>δ</i> , Å	CN
Lu	- 2 Ni	2.852(2)		Ni	– 2 Si	2.374(4)	
	– 1 Ni	2.854(3)			– 1 Si	2.480(7)	
	– 2 Si	2.860(4)			– 1 Si	2.572(7)	
	– 1 Si	2.933(6)			– 2 Lu	2.852(2)	10
	– 2 Si	2.961(4)	16		– 1 Lu	2.854(3)	
	– 1 Ni	2.970(3)	10		– 1 Lu	2.970(3)	
	– 1 Si	3.048(6)			– 2 Lu	3.076(2)	
	– 2 Ni	3.076(2)		Si	- 2 Ni	2.374(4)	
	– 2 Lu	3.4085(15)			– 1 Ni	2.480(7)	
	– 2 Lu	3.5295(7)			– 1 Ni	2.572(7)	
					– 2 Lu	2.860(4)	10
					– 1 Lu	2.933(6)	
					– 2 Lu	2.961(4)	
					– 1 Lu	3.048(6)	

**Table 7** Atom coordinates and isotropic displacement parameters for the compound  $LuNi_{0.61}Si_{1.39}$  (structure type AlB<sub>2</sub>, *hP3*, *P6/mmm*).

Site	Wyckoff position	x	У	Z	$B_{\rm iso},{\rm \AA}^2$			
Lu	1 <i>a</i>	0	0	0	0.48(2)			
$M^{ m a}$	2d	1/3	2/3	1/2	1.36(7)			
<sup>a</sup> $M = 0.307(9)$ Ni	$^{a}M - 0.307(9)$ Ni + 0.693(9)Si							

<sup>a</sup> M = 0.307(9)Ni + 0.693(9)Si.

**Table 8** Interatomic distances and coordination numbers for the compound  $LuNi_{0.61}Si_{1.39}$  (structure type AlB<sub>2</sub>, *hP3*, *P6/mmm*).

Atom

М

 $-3M^{a}$ 

– 6 Lu

Atom		CN	
Lu	$-12 M^{a}$	2.98994(5)	
	– 2 Lu	3.87276(10)	20
	– 6 Lu	3.94594(10)	

<sup>a</sup> M = 0.307(9)Ni + 0.693(9)Si.

# Conclusions

In addition to the previously known six ternary compounds in the system Lu–Ni–Si, three new silicides were found: LuNiSi<sub>3</sub>, LuNiSi, and LuNi<sub>0.61</sub>Si<sub>1.39</sub>. The latter compound has a homogeneity range of LuNi<sub>0.27-0.67</sub>Si<sub>1.73-1.33</sub> at 600°C and is characterized by a statistical mixture of Ni and Si atoms. The former two compounds have point compositions and ordered distribution of the atoms. In the structures of the three new compounds the Si atoms are coordinated by trigonal prisms with three or four additional atoms.

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*δ*, Å

2.27820(6)

2.98994(5)

CN

9

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